

TECHNICAL DATA
DATA SHEET 4803, REV. -

HERMETIC POWER SCHOTTKY RECTIFIER 150°C Maximum Operation Temperature

DESCRIPTION: A 30-VOLT, 35 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-254 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

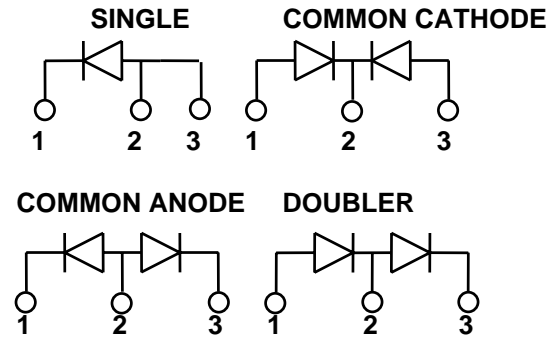
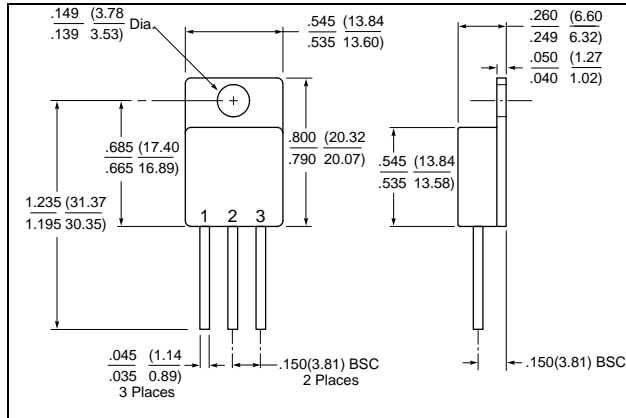
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	30	Volts
MAXIMUM DC OUTPUT CURRENT (@ $T_C=100^\circ\text{C}$) (Single, Doubler)	I_o	35	Amps
MAXIMUM DC OUTPUT CURRENT (@ $T_C=100^\circ\text{C}$) (Common Cathode, Common Anode)	I_o	35	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=8.3ms, Sine)	I_{FSM}	150	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	2635	pF
MAXIMUM THERMAL RESISTANCE (Single)	$R_{\theta JC}$	1.25	$^\circ\text{C/W}$
MAXIMUM THERMAL RESISTANCE (Common Cathode, Common Anode, Doubler)	$R_{\theta JC}$	0.63	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE	Top/Tstg	-55 to + 150	$^\circ\text{C}$
MAXIMUM STORAGE TEMPERATURE RANGE	Top/Tstg	-55 to + 150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 35$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.81 0.84	Volts
MAXIMUM REVERSE CURRENT (I_r @ 30 V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	0.4 230	mA

SENSITRON
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Mechanical Dimensions: In inches / mm



TO-254

PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	CATHODE/ ANODE	CATHODE

Curves shown are for bare die only.

TECHNICAL DATA

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